MOSFET – P-Channel, D²PAK -60 V. -27.5 A

Designed for low voltage, high speed switching applications and to withstand high energy in the avalanche and commutation modes.

Features

- AEC Q101 Qualified NVB25P06
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- PWM Motor Controls
- Power Supplies
- Converters
- Bridge Circuits

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	-60	V
Gate–to–Source Voltage – Continuous – Non–Repetitive (t _p ≤10 ms)	V _{GS} V _{GSM}	±15 ±20	V Vpk
Drain Current – Continuous @ T _A = 25°C – Single Pulse (t _p ≤10 μs)	I _D I _{DM}	27.5 80	A Apk
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	120	W
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to +175	°C
$ Single Pulse Drain-to-Source Avalanche \\ Energy - Starting T_J = 25^\circ C \\ (V_{DD} = 25 V, V_{GS} = 10 V, \\ I_{L(pk)} = 20 A, L = 3 mH, R_G = 25 \Omega) $	E _{AS}	600	mJ
Thermal Resistance – Junction-to-Case – Junction-to-Ambient (Note 1) – Junction-to-Ambient (Note 2)	R _{θJC} R _{θJA} R _{θJA}	1.25 46.8 63.2	°C/W
Maximum Lead Temperature for Soldering Purposes, (1/8" from case for 10 s)	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

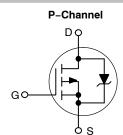
- 1. When surface mounted to an FR4 board using 1" pad size (Cu Area 1.127 in²).
- When surface mounted to an FR4 board using the minimum recommended pad size (Cu Area 0.412 in²).



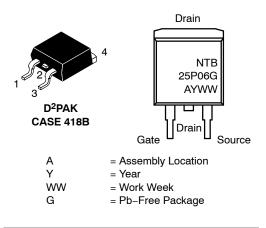
ON Semiconductor®

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V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
–60 V	65 mΩ @ –10 V	–27.5 A



MARKING DIAGRAM & PIN ASSIGNMENT



ORDERING INFORMATION

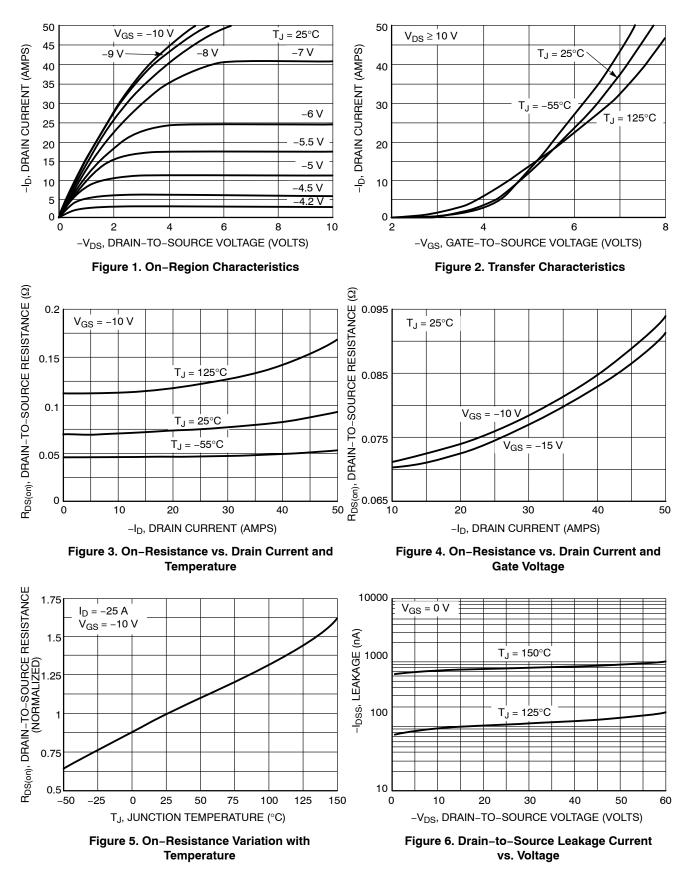
Device	Package	Shipping [†]
NTB25P06T4G	D ² PAK (Pb–Free)	800 / Tape & Reel
NVB25P06T4G	D ² PAK (Pb–Free)	800 / Tape & Reel

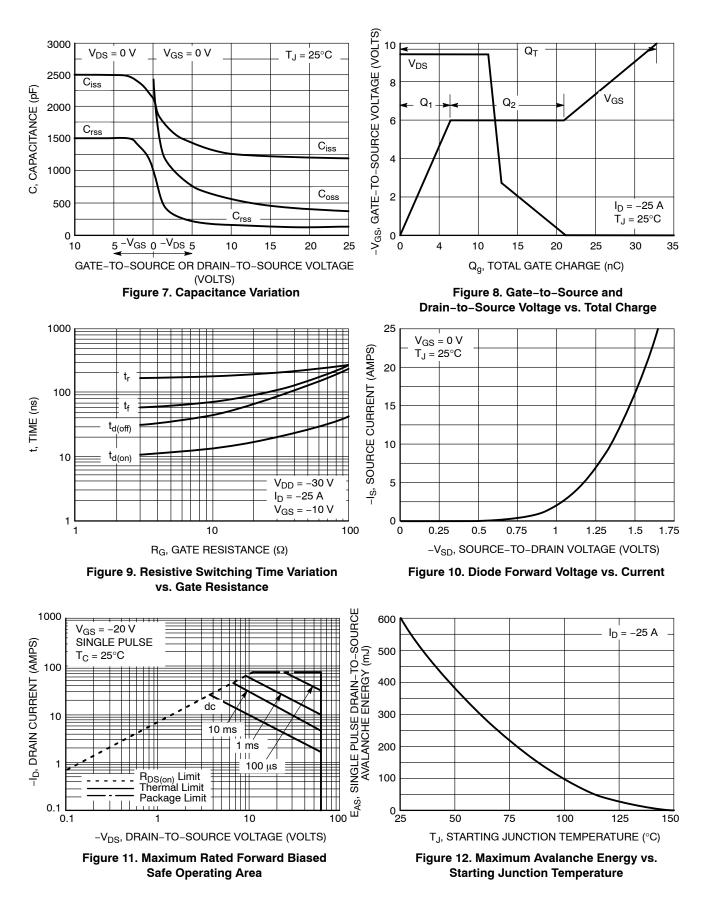
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

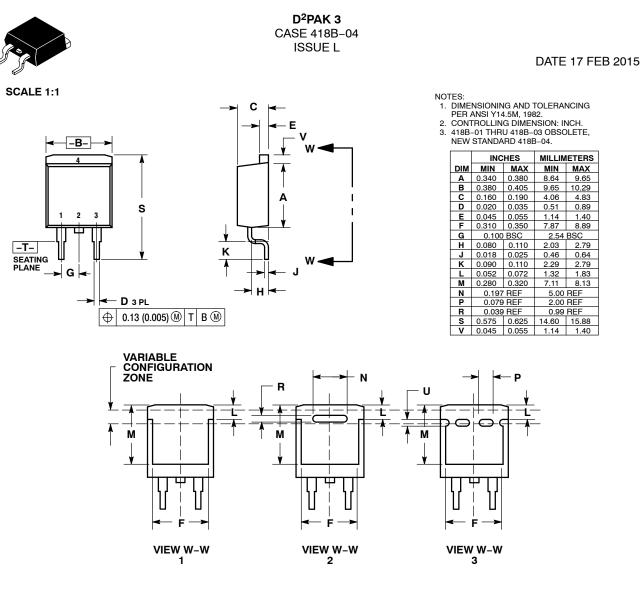
Characteristic			Min	Тур	Мах	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage (Note 3) $(V_{GS} = 0 \text{ V}, I_D = -250 \ \mu\text{A})$ (Positive Temperature Coefficient)		V _{(BR)DSS}	-60 -	_ 64		V mV/°C
Zero Gate Voltage Drain Current $(V_{GS} = 0 V, V_{DS} = -60 V, T_J = 25^{\circ}C)$ $(V_{GS} = 0 V, V_{DS} = -60 V, , T_J = 150^{\circ}C)$		I _{DSS}	- -		-10 -100	μΑ
Gate-Body Leakage Current (V	_{GS} = ±15 V, V _{DS} = 0 V)	I _{GSS}	-	-	±100	nA
ON CHARACTERISTICS (Note 3	3)					
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = -250 \mu A)$ (Negative Threshold Temperature Coefficient)			-2.0 -	-2.8 6.2	-4.0 -	V mV/°C
Static Drain–Source On–State Resistance $(V_{GS} = -10 \text{ V}, I_D = -12.5 \text{ A})$ $(V_{GS} = -10 \text{ V}, I_D = -25 \text{ A})$			-	0.065 0.070	0.075 0.082	Ω
Forward Transconductance $(V_{DS} = -10 \text{ V}, I_D = -12.5 \text{ A})$		gFS	_	13	_	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	1200	1680	pF
Output Capacitance	(V _{DS} = -25 V, V _{GS} = 0 V, F = 1.0 MHz)	C _{oss}	-	345	480	1
Reverse Transfer Capacitance		C _{rss}	_	90	180	
SWITCHING CHARACTERISTIC	CS (Notes 3 & 4)					
Turn-On Delay Time		t _{d(on)}	-	14	24	ns
Rise Time	(V _{DD} = −30 V, I _D = −25 A,	t _r	-	72	118	ns
Turn-Off Delay Time	$V_{GS} = -10 \text{ V } R_G = 9.1 \Omega$	t _{d(off)}	-	43	68	ns
Fall Time		t _f	-	190	320	ns
Gate Charge	(V _{DS} = -48 V, I _D = -25 A, V _{GS} = -10 V)	QT	-	33	50	nC
		Q ₁	-	6.5	-	1
		Q ₂	_	15	-	
BODY-DRAIN DIODE RATINGS	6 (Note 3)					
Diode Forward On-Voltage	$(I_{S} = -25 \text{ A}, V_{GS} = 0 \text{ V})$ $(I_{S} = -25 \text{ A}, V_{GS} = 0 \text{ V}, T_{J} = 150^{\circ}\text{C})$	V _{SD}	- -	-1.8 -1.4	-2.5 -	V
Reverse Recovery Time	(I _S = -25 A, V _{GS} = 0 V, dI _S /dt = 100 A/μs)	t _{rr}	-	70	-	ns
		t _a	-	50	-	
		t _b	-	20	-	
Reverse Recovery Stored Charge		Q _{RR}	_	0.2	-	μC

Indicates Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.









STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. GATE	PIN 1. CATHODE	PIN 1. NO CONNECT
2. COLLECTOR	2. DRAIN	2. CATHODE	2. COLLECTOR	2. ANODE	2. CATHODE
3. EMITTER	SOURCE	ANODE	3. EMITTER	CATHODE	3. ANODE
4. COLLECTOR	4. DRAIN	4. CATHODE	4. COLLECTOR	4. ANODE	4. CATHODE

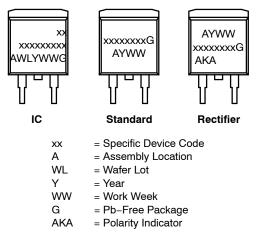
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D²PAK 3 CASE 418B-04 ISSUE L

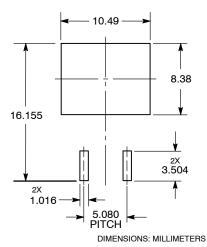
DATE 17 FEB 2015

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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